



Cite this: *Phys. Chem. Chem. Phys.*,
2020, 22, 28459

More than protection: the function of TiO₂ interlayers in hematite functionalized Si photoanodes†

Anurag Kawde,^a Alagappan Annamalai,^e Anita Sellstedt,^f Jens Uhlig,^d
Thomas Wågberg,^e Pieter Glatzel^{*b} and Johannes Messinger^{†ag}

Worldwide significant efforts are ongoing to develop devices that store solar energy as fuels. In one such approach, solar energy is absorbed by semiconductors and utilized directly by catalysts at their surfaces to split water into H₂ and O₂. To protect the semiconductors in these photo-electrochemical cells (PEC) from corrosion, frequently thin TiO₂ interlayers are applied. Employing a well-performing photoanode comprised of 1-D n-Si microwires (MWs) covered with a mesoporous (mp) TiO₂ interlayer fabricated by solution processing and functionalized with α -Fe₂O₃ nanorods, we studied here the function of this TiO₂ interlayer by high-energy resolution fluorescence detected X-ray absorption near edge structure (HERFD-XANES) spectroscopy, along with X-ray emission spectroscopy (XES) and standard characterization techniques. Our data reveal that the TiO₂ interlayer not only protects the n-Si MW surface from corrosion, but that it also acts as a template for the hydrothermal growth of α -Fe₂O₃ nanorods and improves the photocatalytic efficiency. We show that the latter effect correlates with the presence of stable oxygen vacancies at the interface between mp-TiO₂ and α -Fe₂O₃, which act as electron traps and thereby substantially reduce the charge recombination rate at the hematite surface.

Received 12th August 2020,
Accepted 22nd November 2020

DOI: 10.1039/d0cp04280c

rsc.li/pccp

Introduction

Solar-driven photo-electrochemical (PEC) water splitting is one of the most promising routes for producing green fuels, such as hydrogen.^{1,2} Efficient PEC devices frequently employ co-catalyst decorated semiconductor photo-electrodes to harvest solar energy and to split water into hydrogen and oxygen. In the search for the most efficient photoelectrode for PEC applications, semiconductors like TiO₂,^{3,4} α -Fe₂O₃,^{5–7} p/n Si,^{8–10} WO₃,¹¹ CuO₂,^{12,13} BiVO₄^{14–17} and Ta₃N₅^{18,19} have been studied since Fujishima and Honda⁴ first demonstrated the approach in 1972.

To address potential scalability requirements of the PEC water splitting system, photo-electrodes comprising earth-abundant elements are frequently studied. Manufacturing the components employing solution-based techniques may contribute to further lower the costs of the production process. Examples for earth abundant components employed are silicon (Si) and hematite (α -Fe₂O₃), which under one sun illumination have theoretical solar conversion efficiencies of ~43% and ~15%, respectively.^{20,21} However, the stability of Si in the aqueous condition is low,²² and thus protective layers of, for instance, Ti,²³ Ni,²⁴ NiO_x,²⁵ or TiO₂^{8,22,26,27} have been applied. The thickness of the most frequently used TiO₂ layers varies from ~2 to 130 nm.²⁸ It was initially believed that thick TiO₂ films might act as insulators. However, comprehensive studies by the groups of Lewis,^{27,28} Tilly,^{29,30} and Chorkendorff^{31,32} demonstrate that even TiO₂ layers exceeding 100 nm thickness efficiently transfer charges.²⁹ Interestingly, our recent study of variously functionalized p-Si microwires photoelectrodes indicates that their performance in seawater splitting was even enhanced by a ~50 nm thick mesoporous TiO₂ interlayer.⁸ Apparently, the role of the TiO₂ protective layer seems to be more versatile and sophisticated than previously assumed. So far, the role of the TiO₂ protective layer has been primarily studied by photo-electrochemical techniques,^{33,34} such as Mott-Schottky measurements³⁵ and incident photon-to-current efficiency measurements (IPCE),³⁶ which both give an integral view of the TiO₂ layer. However, there is still

^a Umeå University, Faculty of Science and Technology, Department of Chemistry, Sweden

^b European Synchrotron Radiation Facility, Grenoble, France.
E-mail: pieter.glatzel@esrf.fr

^c Lund Institute of advanced Neutron and X-Ray Science, Lund University, Sweden

^d NanoLund and Chemical Physics, Department of Chemistry, Lund University, Sweden

^e Umeå University, Faculty of Science and Technology, Department of Physics, Sweden

^f Umeå University, Faculty of Science and Technology, Department of Plant Physiology, Umeå Plant Science Centre (UPSC), Umeå, Sweden

^g Molecular Biomimetics, Department of Chemistry – Ångström Laboratory, Uppsala University, Sweden. E-mail: johannes.messinger@kemi.uu.se

† Electronic supplementary information (ESI) available. See DOI: 10.1039/d0cp04280c



a lack of understanding from a fundamental atomic level electronic structure perspective.

Using an all solution-based approach, we prepared an n-Si MWs/mp-TiO₂/α-Fe₂O₃ photoanode with highly competitive photo-electrochemical performance and employed it to understand the multiple roles of the TiO₂ interlayer. Our findings suggest that the TiO₂ interlayer not only stabilizes the photoanode, but that the mesoporous (mp) morphology of TiO₂ also acts as a template for the uniform and high surface area hydrothermal growth of the α-Fe₂O₃ co-catalyst. Furthermore, the presence of the mp-TiO₂ interlayer helps to suppress the exciton charge recombination between n-Si MWs photoelectrodes and co-catalysts, which results in better charge transfer kinetics at the electrode/electrolyte interface for water oxidation. High-energy resolution fluorescence detected X-ray absorption near edge structure (HERFD-XANES), and valence-to-core X-ray emission spectroscopy (vte-XES) at the Ti K-edge demonstrate significant electronic structural changes. At the same time, the Fe K-edge shows little change indicating that the Fe electronic structure is hardly affected by mesoporous TiO₂. Our data suggest that the modification of the electronic structure in the TiO₂ interlayer leads to the exceptional photo-electrochemical performance of our functionalized n-Si photoanode during water oxidation.

Results and discussion

Preparation, morphology, and elemental characterization of functionalized n-Si MWs

A 1-D microwire structure (n-Si MWs) on the surface of a planar n-Si was obtained by treating small pieces of n-Si wafers (2 × 2 cm²) with an etching electrolyte comprised of HF and AgNO₃ following a previously published procedure (see ESI† for further details).³⁷ The resulting n-Si MWs were then spin-coated with a TiO₂ sol-gel,^{8,38,39} resulting in n-Si MWs/mp-TiO₂ photoelectrodes. In this process, the block-co-polymer formed spherical micelles that supported the formation of a mesoporous structure of the protective TiO₂ layer (Fig. SI 1, ESI†). The cross-sectional SEM image in Fig. 1a shows that the MWs have a length of about 25 μm and that the TiO₂ coating was complete, yet thin enough not to remove the spacing between the MW. A magnified view of the TiO₂ coating is presented in Fig. 1b. Onto this mesoporous TiO₂ surface, hematite nanorods were hydrothermally grown⁴⁰ (see ESI† for further details). The morphology of the resulting n-Si MWs/mp-TiO₂/α-Fe₂O₃ is shown in Fig. 1c and d. It can be seen that despite the acidic conditions during the hydrothermal treatment, the MWs remained mostly intact and that a uniform coverage with ca. 200 nm long Fe₂O₃ nanorods were obtained. The excellent coverage of the MW with small, similarly sized α-Fe₂O₃ nanorods suggests that the mesopores of mp-TiO₂ acted as templates for nanorod formation by serving as nucleation sites (see also below). After the synthesis, the samples were annealed at 380 °C, so that the Fe₂O₃ nanorods were converted majorly to alpha hematite (α-Fe₂O₃), as confirmed by X-ray photoelectron spectroscopy (see details in Fig. SI 2, ESI†) and HERFD-XANES (Fig. SI 8 and 9, ESI†). The UV-vis absorption

spectrum for bare α-Fe₂O₃ nanorods is presented in Fig. SI 6 c, ESI†).

Fig. 1e shows that in the absence of the TiO₂ layer, the n-Si MWs were partially dissolved by the acidic iron precursor and that about 5 times larger α-Fe₂O₃ rods (ca. 1 μm) were obtained that lacked good contact to the n-Si MWs. The increased size of α-Fe₂O₃ nanorod/crystallites is likely due to the significantly fewer nucleation sites provided by n-Si MWs as compared to n-Si MWs/mp-TiO₂.

To test if the surface morphology of the TiO₂ interlayer is indeed essential for an even growth of α-Fe₂O₃ nanorods, we also prepared a photoanode covered by an amorphous TiO₂ layer (n-Si MWs/a-TiO₂/Fe₂O₃). For this, a commercial titanium diisopropoxide bis(acetylacetonate) solution (diluted with ethanol) was applied using a similar spin-coating cycle as for making mp-TiO₂.^{6,8} Due to the absence of a block co-polymer like pluronic P123, which is known to promote mesopore formation,^{38,39} and due to the lower viscosity of the commercial precursor solution, the resulting TiO₂ film on the n-Si MWs was amorphous (a-TiO₂) and less-even compared to the sol-gel approach. The electron microscopic image in Fig. 1f shows that although the a-TiO₂ interlayer largely protected the n-Si MW during the hydrothermal treatment, fewer Fe₂O₃ crystallites formed on its surface. In addition, the Fe₂O₃ crystallites were of varying size and shape, with less good contact to the a-TiO₂ surface as compared to mp-TiO₂ (Fig. 1d). These results further confirm that mp-TiO₂ acts, *via* its mesopores, as a template for an even and dense hydrothermal growth of well-connected Fe₂O₃ nanorods on top of the MWs. This is important for providing a large catalytic surface and for minimizing the charge carrier transport pathways within Fe₂O₃.^{41,42}

Based on this structural inspection, we confirmed that mesoporous TiO₂ protects n-Si MWs in acidic media,^{27,43} and propose that it also provides essential nucleation sites for the growth of uniform and well-connected Fe₂O₃ nanorods.

Photo-electrochemical characterization

The PEC performance of the n-Si MWs/mp-TiO₂/α-Fe₂O₃ photoanode was systematically compared to various control samples, such as bare planar n-Si, bare n-Si MWs, n-Si MWs/mp-TiO₂, n-Si MWs/α-Fe₂O₃ and n-Si MWs/a-TiO₂/α-Fe₂O₃. The photocurrent densities (*J*_{ph}) obtained in aqueous 1 M NaOH electrolyte at one sun illumination and an applied potential of 1.23 V_{RHE} (using a Pt counter electrode) are shown in Fig. 2 (see ESI† for further details). The corresponding *I/V* curves are displayed in Fig. SI 3 and SI 4 (ESI†). Fig. 2 shows that for bare planar n-Si the *J*_{ph} was 0.5 mA cm⁻², and that *J*_{ph} increased to 0.8 mA cm⁻² for bare n-Si MWs, reflecting the expected improved light absorption and charge-transfer capabilities of the microwire morphology.⁸ Interestingly, mp-TiO₂ sol-gel coating of the n-Si MWs led to a further increase of *J*_{ph} to 1.01 mA cm⁻². Most importantly, we noted a significant rise in *J*_{ph} to 4 mA cm⁻² (±0.02 mA cm⁻²) when the n-Si MWs/mp-TiO₂ were additionally decorated with α-Fe₂O₃ nanorods. In the absence of the protective TiO₂ layer, the photocurrent dropped to 1.2 mA cm⁻² for n-Si MWs/α-Fe₂O₃, while the n-Si MW/a-TiO₂/α-Fe₂O₃



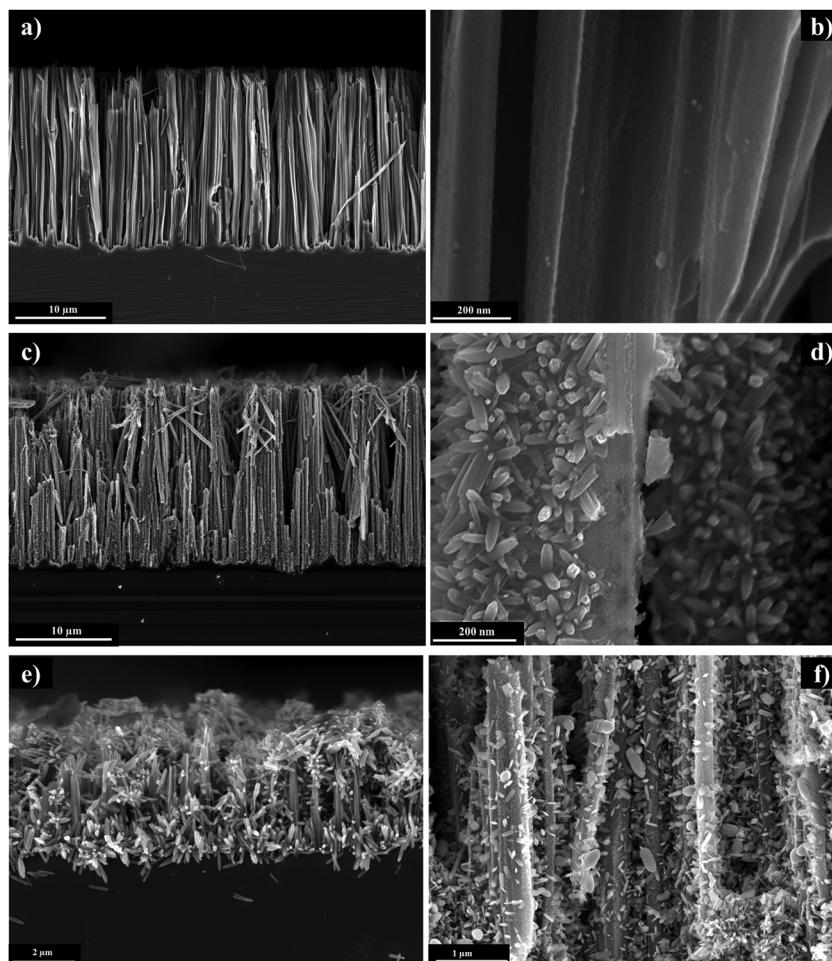


Fig. 1 Cross-sectional SEM images of (a and b) n-Si MWs/mp-TiO₂, (c and d) n-Si MWs/mp-TiO₂/α-Fe₂O₃, (e) n-Si MWs/α-Fe₂O₃ and (f) n-Si MWs/a-TiO₂/α-Fe₂O₃.

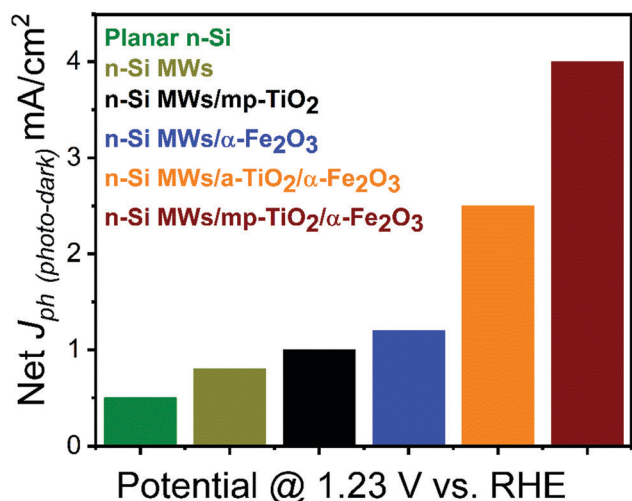


Fig. 2 Net photocurrent responses for bare and functionalized n-Si photoelectrodes at 1.23 V_{RHE}.

photoanode reached a photocurrent of 2.5 mA cm⁻², still clearly below the values achieved with a mp-TiO₂ protection layer.

To confirm solar-assisted water splitting, the photogenerated gases were analyzed by sampling the headspace with gas chromatography during a chronoamperometry (at 1.23 V_{RHE}; Fig. SI 5, ESI[†]). After a short onset period, a nearly stable photocurrent of about 4 mA cm⁻² was observed for the n-Si MW/mp-TiO₂/α-Fe₂O₃ photoanode over the entire sampling period of 2 hours. The accumulated amounts of photogenerated hydrogen and oxygen collected from the headspace of the PEC cell were 4.33 and 2.2 mmol cm⁻² (Fig. SI 5b, ESI[†]), corresponding to faradaic efficiencies of 94% and 97%, respectively.

The TiO₂ interlayer also significantly lowered the onset potential, which we defined here as the potential at which the net photocurrent density reached 0.1 mA cm⁻². The value for n-Si MW/mp-TiO₂/α-Fe₂O₃ was only 0.27 V_{RHE} (Fig. SI 3b, ESI[†]), which is, to the best of our knowledge, the lowest reported onset potential for an undoped α-Fe₂O₃ nanorod based photoanode. In the absence of the mp-TiO₂ interlayer, the onset potential was 540 mV higher (0.81 V_{RHE}; Fig. SI 3b, ESI[†]). The onset potential for an electrode comprising similar α-Fe₂O₃ nanorods grown on FTO substrate with an a-TiO₂ interlayer was found to be 0.77 V_{RHE}.^{6,44} The above experiments indicate that the low onset potential and high J_{ph} reported here may come from having a dual absorber PEC system made of uniformly



sized Fe_2O_3 nanorods that are well connected to the n-Si MWs *via* mp-TiO₂.

To test if the bandgaps of both Si and Fe_2O_3 contribute to the light absorption and thus J_{ph} of the n-Si MW/mp-TiO₂/ α - Fe_2O_3 photoelectrode, this multilayer system was selectively excited at either 455 nm, to probe the contribution of the α - Fe_2O_3 nanorods, or at 625 nm for testing the performance if only the n-Si MWs absorbed light (Fig. SI 6, ESI†). Employing 455 nm illumination at 100 mW cm^{-2} , we found that at 1.23 V_{RHE} J_{ph} was 2.4 mA cm^{-2} , which was almost 60% of the photocurrent obtained at 1 sun illumination (Fig. SI 6, ESI†). This indicates that under these experimental conditions the α - Fe_2O_3 nanorods were not simply dark OER catalyst, but instead acted as photo absorbers, while n-Si MWs functioned mainly as a conductive substrate. However, we cannot exclude the possibility that some photons were absorbed also by Si at 455 nm.⁴⁵ Importantly, essentially no dark currents were observed for the n-Si MWs/mp-TiO₂/ α - Fe_2O_3 photoanode up to at least a potential of 2.5 V_{RHE} (Fig. SI 3c, ESI†). Next, we illuminated our photoanode at 625 nm (100 mW cm^{-2}) to selectively excite Si. At 1.23 V_{RHE} J_{ph} was found to be 3.7 mA cm^{-2} (Fig. SI 6a and b, ESI†), which is 93% of the photocurrent obtained with 1 sun illumination (4.0 mA cm^{-2}).

The capacity of the n-Si MWs/mp-TiO₂/ α - Fe_2O_3 photoanode to act as a dual solar absorber system became more apparent when the same experiment was repeated at 2.5 V_{RHE} . Here, the J_{ph} reached 20 mA cm^{-2} under 1 sun illumination. The photocurrent was 20% lower if only the n-Si MWs were excited, and nearly 40% lower if predominantly the α - Fe_2O_3 nanorods were excited (Fig. SI 6, ESI†). We thus conclude that our n-Si MWs/mp-TiO₂/ α - Fe_2O_3 photoanode acts as dual absorber system, which is in line with a recent study on another hematite/Si nanowire PEC system.⁴⁵ This is schematically illustrated in Fig. 3.

For comparison, Xiaopeng Qi *et al.*⁴⁶ reported an n-Si/ α - Fe_2O_3 core-shell structure with 25 μm long Si MWs with a J_{ph} of 5.28 mA cm^{-2} at 1.23 V_{RHE} and an onset potential of 0.5 V_{RHE} recorded with a scan rate of 50 mV s^{-1} . For the scan rate of 20 mV s^{-1} used in this study, Xiaopeng Qi *et al.*⁴⁶ reported a J_{ph} of $\sim 3.8 \text{ mA cm}^{-2}$ at 1.23 V_{RHE} with an onset potential of 0.5 V_{RHE} , which is almost twice the onset potential reported in this study. Recently, Zhongyuan Zhou *et al.*⁴⁷ achieved a maximal J_{ph} of 3.12 mA cm^{-2} at 1.23 V_{RHE} and an onset potential of 0.15 V_{RHE} for a Sn-doped hematite film grown on Si MWs, whereas their pristine n-Si/ α - Fe_2O_3 photoanode had an onset potential of 0.85 V_{RHE} .

Insight into the mechanism by which TiO₂ improves the performance of photoanodes can be gained by studying the transient photo-response of α - Fe_2O_3 functionalized n-Si MWs without (Fig. 4a and b) and with (Fig. 4c and d) the mp-TiO₂ interlayer. The transient photocurrent density at 1.5 V_{RHE} (2-electrode set-up) was nearly three-fold higher for n-Si MW/mp-TiO₂/ α - Fe_2O_3 (6 mV cm^{-2}) than for n-Si MW/ α - Fe_2O_3 (2.2 mV cm^{-2}), which is fully consistent with the data in Fig. 2. The sharp spikes visible for both samples in the anodic (positive-spike) and cathodic (negative-spike) regions arise due to the light-induced generation and the dissipation of charge

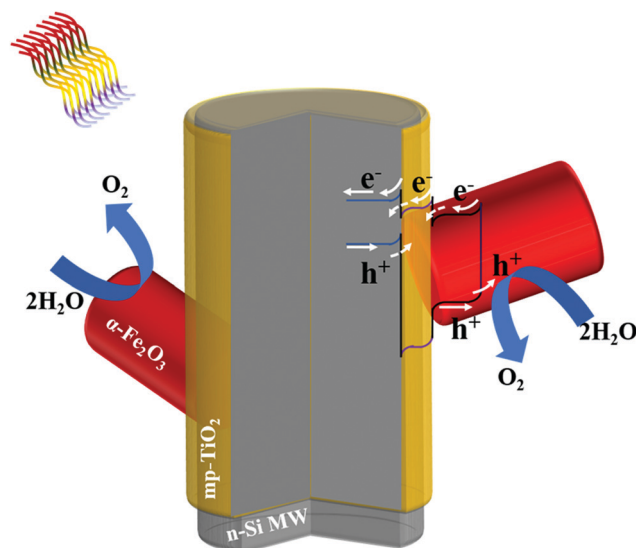


Fig. 3 A schematic representation of energy diagrams and charge-carrier mobility in the n-Si MW/mp-TiO₂/ α - Fe_2O_3 photoelectrode.

carriers at the electrode/electrolyte interface. When zooming into the regions of the anodic spikes, it is seen that nearly twice as many charges dissipated in the device lacking the mp-TiO₂ layer, and that this process occurred over a significantly longer time period (Fig. 4b and d). Thus, the presence of a mp-TiO₂ interlayer appears to block the mobility of the holes photo-generated in α - Fe_2O_3 towards the n-Si MWs, since the valence band of mp-TiO₂ lies at lower energy than in α - Fe_2O_3 (Fig. 5b). Assuming the same exciton generation with and without the TiO₂ layer (as the thin TiO₂ layer is optically transparent), the addition of the wide bandgap TiO₂ interlayer thus reduced unproductive charge recombination and thereby allowed

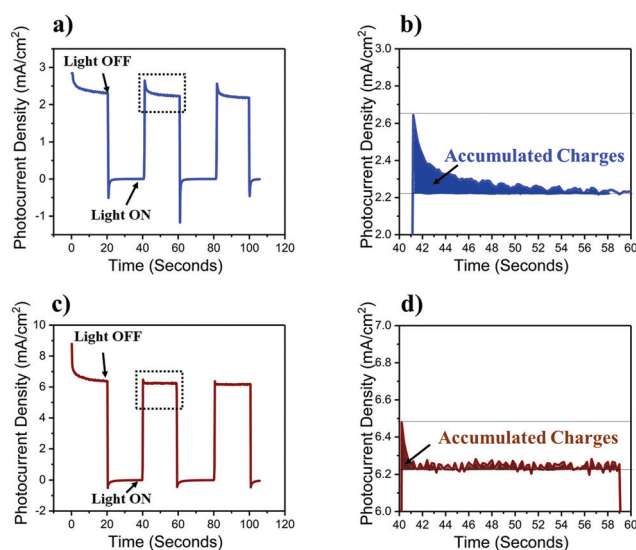


Fig. 4 Transient photocurrent response recorded at 1.5 V_{RHE} . (a) n-Si MW/ α - Fe_2O_3 and (b) n-Si MW/mp-TiO₂/ α - Fe_2O_3 . (c and d) Magnified views of representative anodic spikes.

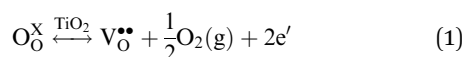


utilizing the photogenerated holes more efficiently for water oxidation.

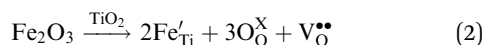
In summary, besides the well-known function of the TiO₂ protection layer in passivating the surface defects on Si MWs,^{8,32,33} we tentatively assign the superior performance of n-Si MW/mp-TiO₂/α-Fe₂O₃ as compared to n-Si MW/α-Fe₂O₃ to a better interfacial connection between mp-TiO₂ and α-Fe₂O₃, the creation of stable oxygen vacancies (electron traps) in the mp-TiO₂ interlayer, and to the low band edge positioning of TiO₂ that likely suppresses the hole mobility from α-Fe₂O₃ towards n-Si.³²

Oxygen vacancies

Various studies discussed the role of surface oxygen vacancies in Fe/TiO₂ nanoparticles.^{48–51} They establish that oxygen vacancies are generated by high-temperature annealing (~400 °C) of TiO₂ in oxygen-deficient atmospheres. This process can be described using the Kröger-Vink notations:^{51–53}



Eqn (1) is a reversible reaction, meaning that the surface oxygen vacancies (V_O^{••}) disappear gradually in ambient conditions (in the presence of molecular oxygen). Early studies from Grätzel and co-workers,^{49,54} and Hoffmann and co-workers⁵⁰ suggested stabilization of surface oxygen vacancies in the nanoparticulate TiO₂ lattice by the introduction of acceptor type dopants such as Fe³⁺ as ionic charge-compensating species represented by eqn (2):



Previous studies have already correlated the presence of oxygen vacancies in TiO₂ with enhanced photocatalytic properties of TiO₂.^{48,52} Additionally, increasing the active surface area of TiO₂ particles by reducing their size has also been employed for enhancing photocatalytic properties of TiO₂.^{55,56} As mp-TiO₂ thin films are known for having an about 800 times larger effective surface area than planar TiO₂ thin films,^{48,57,58} the incorporation of Fe ions onto mp-TiO₂ thin films may prove to be an effective strategy for stabilizing oxygen vacancies, and to thereby enhance photocatalytic water oxidation efficiency. In

our study, the Fe ions were incorporated onto the surface layers of mp-TiO₂ during the hydrothermal growth of α-Fe₂O₃ nanorods onto the surface of mp-TiO₂ and the subsequent annealing at 380 °C in an oxygen-deficient atmosphere.

High energy resolution fluorescence detected X-ray absorption near edge structure (HERFD-XANES) and valence to core X-ray emission spectroscopy (vtc-XES)

To provide further evidence for the oxygen vacancies and to study what electronic structure changes they cause in TiO₂, we performed HERFD-XANES and X-ray emission spectroscopy at beamline ID26 of the European Synchrotron Radiation Facility (ESRF). HERFD-XANES spectra were obtained at the Ti K-edge for bare mp-TiO₂, mp-TiO₂ coated on planar n-Si (planar n-Si/mp-TiO₂), n-Si MWs/mp-TiO₂, and n-Si MWs/mp-TiO₂/α-Fe₂O₃ (Fig. SI 7, ESI†). HERFD-XANES spectra at the Fe K-edge were recorded for bare α-Fe₂O₃, n-Si MWs/α-Fe₂O₃, and n-Si MWs/mp-TiO₂/α-Fe₂O₃ (Fig. SI 8 and SI 9, ESI†). All spectra were normalized to their total area. The spectra were not corrected for over- (or self-) absorption effects that may significantly distort the spectra of the bare oxides. The spectra are thus also presented as first derivatives in order to facilitate comparison.

The Fe K-edge HERFD-XANES taken of all samples are essentially superimposable (Fig. SI 8 and SI 9, ESI†), indicating that neither the deposition of Fe₂O₃ onto mp-TiO₂ nor Si MWs had a significant effect on the electronic structure of α-Fe₂O₃. Similarly, the first derivatives of the Ti K-edge HERFD-XANES spectra of bare mp-TiO₂ and n-Si MWs/mp-TiO₂ are nearly identical (Fig. SI 7, ESI†). This indicates that the contact with the n-Si MWs did not induce significant electronic structural changes in the TiO₂ lattice.

By contrast, the Ti K-edge HERFD-XANES data reveal that the hydrothermal growth of α-Fe₂O₃ nanorods onto mp-TiO₂ strongly influences the electronic structure of mp-TiO₂, as shown in Fig. 6a and b. For Ti, the XANES pre-edge peaks in the energy range of ~4966 to ~4976 eV reflect core electron transition to Ti-3d4p hybridized states, which are highly sensitive to the local geometry of the Ti centers.^{59,60} The pre-edge peak A1 corresponds to the transition of a Ti 1s electron into a t_{1g} band-like state. The small low energy shoulder on the A2 peak (A2*) is due to 1s-e_g excitation, while the 1s electron

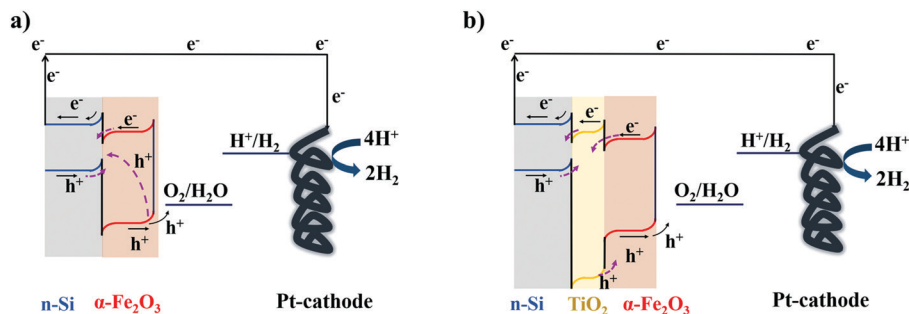


Fig. 5 Schematic band bending diagrams for functionalized n-Si photoanode under an applied anodic bias of 1.5 V. (a) n-Si MWs/α-Fe₂O₃ and (b) n-Si MWs/TiO₂/α-Fe₂O₃ depict the charge carrier transfer under one sun illumination. The possible charge carrier recombination pathways are shown with dashed purple arrows.



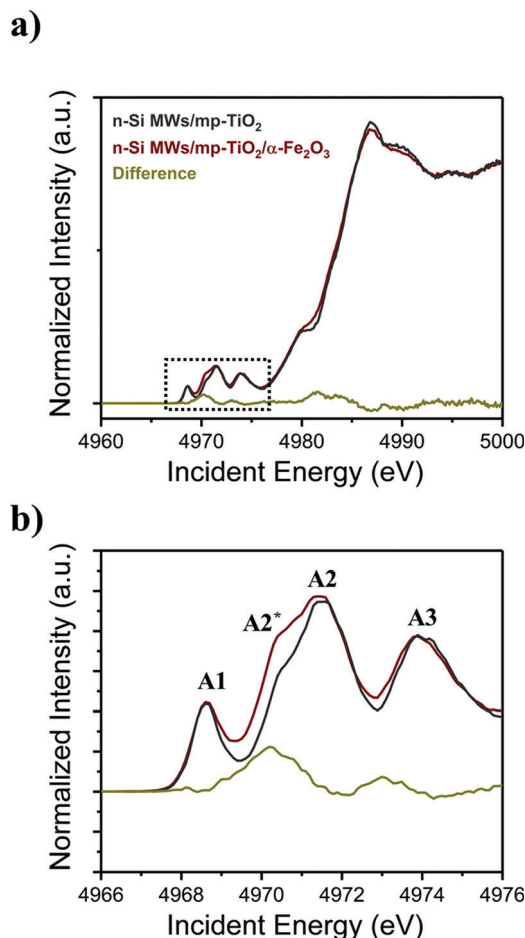


Fig. 6 (a) HERFD-XANES spectra acquired for functionalized n-Si MWs photoanodes at the Ti K-edge, (b) magnified view of the pre-edge region. Additional control spectra are displayed in Fig. SI 7 (ESI†).

excitation to crystal field split d-states on the neighboring Ti atoms results in the main A2 and the A3 peaks.^{61,62} The A3 peak corresponds to an e_g band-like state, which is due to pure non-local excitation. The non-local excitations are mediated by oxygen nearest neighbors.^{63,64} The surrounding oxygen thus influences all the pre-edge peaks in the Ti K-edge.^{59,65–68}

Comparison of the pre-edge features of the n-Si MWs/mp-TiO₂ photoelectrodes with (red line) and without (grey line) α -Fe₂O₃ nanorods (Fig. 6b) reveals that the A2* peak becomes significantly more prominent when α -Fe₂O₃ nanorods are present. At the same time, the other features are unchanged, indicating no significant structural changes. As the A2* peak arises from a $1s \rightarrow e_g$ excitation, the presence of a stronger A2* peak in n-Si MWs/mp-TiO₂/ α -Fe₂O₃ is attributed to the creation of oxygen vacancies at the mp-TiO₂ and α -Fe₂O₃ interface that leads to a distortion of the local coordination which increases the mixing of metal p and d orbitals.⁴⁸ The absence of a shift of the main K-edge shows that the Ti–O distances, on average, do not change,^{68,69} indicating that the bulk of the Ti remains in oxidation state Ti⁴⁺.

In line with our results, Ghaffari *et al.*⁷⁰ reported that the increase in the Ti K-edge A2* pre-edge peak intensities correlates with improved photocatalytic properties of their SrTi_(1- λ)Fe _{λ} O_(3- δ) system, which are caused by oxygen vacancies or defects. As the vacancies were created during the hydrothermal growth of α -Fe₂O₃ nanorods and subsequent annealing at 380 °C, we propose that they are restricted to the interface between mp-TiO₂ and α -Fe₂O₃. The band-bending physics presented in Fig. 5b shows that these oxygen vacancies could trap part of the electrons photogenerated in the α -Fe₂O₃ nanorods. This would then effectively inhibit the recombination of charge-carriers in the α -Fe₂O₃ nanorods, leaving the photogenerated holes available for enhanced water oxidation.

To comprehend further the changes in the electronic structure of the mp-TiO₂ interlayer caused by growing Fe₂O₃ nanorods onto it, X-ray emission spectroscopy (XES) was performed at the Ti and Fe K-edges. The K β fluorescence lines for Ti are shown in Fig. 7, while the Fe K β -XES is displayed in Fig. SI 10 (ESI†). Fig. 7b shows that the 3p to 1s core-shell-to-core-shell (K β _{1,3}) line of Ti is invariant to the presents of Fe₂O₃ nanorods, and the same is observed for the corresponding Fe signal (Fig. SI 10b, ESI†). As K β _{1,3} lines are known to be sensitive to the local spin and thus the oxidation state, the absence of a detectable change indicates that the local distortion of the oxygen environment does not involve redox changes of Ti⁴⁺ or Fe³⁺, in line with the observation in the XANES data. The valence-to-core emission lines at higher energies (Fig. 7c and d) arise from metal–ligand mixed orbitals and directly probe the ligand environment. Here we do observe changes for Ti, in agreement with the K absorption pre-edge spectral changes. It is important to note that the maximum amount of TiO₂ that can interact with a \sim 20 nm diameter α -Fe₂O₃ nanorods is \sim 20%; for detailed calculation, see the ESI†. The percentage of Ti atoms changing the local coordination as derived from the spectral changes in Fig. 6 is in approximate agreement with the estimated interaction of mp-TiO₂ with α -Fe₂O₃ nanorods. Thus, we suggest that the oxygen vacancies created in mp-TiO₂ are restricted to the interfacial boundary between mp-TiO₂ and the α -Fe₂O₃ nanorods. This suggests that Fe³⁺ ions can stabilize oxygen vacancies at this interface, which in turn prevent electron–hole recombination and thereby enhance the water oxidation activity.^{49,50,71–74}

We found that electronic structural changes take place in the mp-TiO₂ when sandwiched between n-Si MW and α -Fe₂O₃, while the Fe-edge hardly changed. This indicates that the improved photocatalysis arises from improved carrier transport within the device rather than a lowered barrier for water splitting at α -Fe₂O₃. This is consistent with our recent finding that p-Si MWs/TiO₂ photocathodes undergo significant changes when decorated with NiO_x or CoO_x.⁸ Thus, our study paves the way towards understanding the crucial role of the TiO₂ interlayer by providing X-ray spectroscopic evidence for the stabilization of oxygen vacancies by the application of Fe₂O₃.



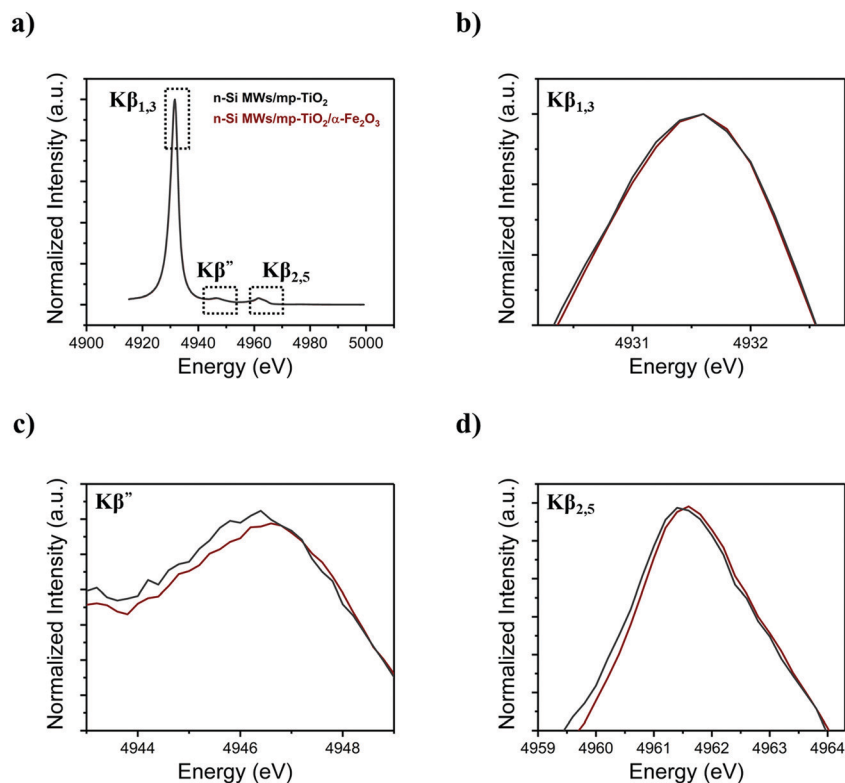


Fig. 7 Ti K β XES spectra acquired for functionalized n-Si MWs photoanodes with (a) K β main and vtc-XES, (b) K $\beta_{1,3}$, (c) K β' and (d) K $\beta_{2,5}$.

Conclusions

In conclusion, we report here a dual solar photon absorber system comprised of n-Si MWs and α -Fe₂O₃. The n-Si MWs and the α -Fe₂O₃ were connected by a thin mp-TiO₂ layer, which acted as a template for the growth of α -Fe₂O₃ nanorods. In the absence of the mp-TiO₂ interlayer, the overall photo-electrochemical performance of α -Fe₂O₃ functionalized n-Si MWs was significantly reduced. Favorable band bending in the n-Si MWs/mp-TiO₂/ α -Fe₂O₃ photoanodes was found to be the critical factor for decreasing the charge recombination and thus increasing the availability of holes for water oxidation. A thorough investigation using X-ray spectroscopy suggests that the hydrothermal growth of α -Fe₂O₃ nanorods on n-Si MWs/mp-TiO₂ with subsequent annealing at 380 °C led to favorable changes in the electronic structure of mp-TiO₂. By contrast, the electronic structure of α -Fe₂O₃ was hardly affected by mp-TiO₂. In summary, the mp-TiO₂ interlayer presented in this study acts (i) as a protective layer for n-Si MWs, (ii) as a template for the uniform and high surface area hydrothermal growth of the α -Fe₂O₃ nanorods, and (iii) in combination with Fe₂O₃, it suppresses charge recombination at the mp-TiO₂/ α -Fe₂O₃ interface *via* stabilized oxygen vacancies (electron traps).

We expect that, in the future, this multi-functionality of the TiO₂ interlayer can be utilized in developing further improved photo-electrodes. As exemplified here, the detailed X-ray spectroscopic

characterization of the photoelectrodes will be a crucial analytical tool in this process.

Author contribution

A. K., A. A., T. W., P. G., J. M. conceptualize and conceived the project. A. K. prepared all the samples and collected SEM images. A. K. and A. A. performed all the photo-electrochemical experiments. A. K. and A. S. analyzed the GC data. A. K. and P. G. performed a synchrotron experiment and collected HERFD-XANES and XES data. A. K., J. U., P. G. processed and analyzed HERFD-XANES, XES, and XPS data. A. K., and J. U. estimated and compared the fractional contact between mp-TiO₂ and α -Fe₂O₃ nanorods. P. G., and J. M. supervised the research work and discussed the results. A. K., P. G., and J. M. co-wrote the manuscript with important inputs from the co-authors.

Conflicts of interest

The authors declare no competing financial interest.

Acknowledgements

The authors thank Andrey Shchukarev for collecting the XPS data. The SEM images were obtained at the Umeå Core Facility for Electron Microscopy (UCEM). The authors thank European



Synchrotron Radiation Facility for granting beamtime and the ID26 beamline staff for assistance during the experiments. The Knut and Alice Wallenbergs Foundation (Artificial Leaf Project; KAW 2011.0055) provided financial support. T. W. acknowledges support from Vetenskapsrådet (2017-04862), and Energimyndigheten (45419-1).

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